

## SCOPE: PRECISION QUAD SPST ANALOG SWITCH

<u>Device Type</u>	<u>Generic Number</u>
01	MAX391MJE/883B
02	MAX392MJE/883B
03	MAX393MJE/883B

**Case Outline(s).** The case outlines shall be designated in Mil-Std-1835 and as follows:

<u>Outline Letter</u>	<u>Mil-Std-1835</u>	<u>Case Outline</u>	<u>Package Code</u>
JE	GDIP1-T16 or CDIP2-T16	16 LEAD CERDIP	J16

### Absolute Maximum Ratings

Voltage Referenced to V<sup>-</sup>

V <sup>+</sup> .....	-0.3V to +17V
GND .....	-0.3V to +17V
GND .....	-0.3V to (V <sup>+</sup> +0.3V)
V <sub>IN</sub> , V <sub>COM</sub> , V <sub>NC</sub> , V <sub>NO</sub> 1/ .....	V- to V+
Current, Any terminal .....	30mA
Peak Current, COM, NO, NC (Pulsed at 1ms, 10% duty cycle max) .....	100mA
Lead Temperature (soldering, 10 seconds) .....	+300°C
Storage Temperature .....	-65°C to +150°C
Continuous Power Dissipation .....	T <sub>A</sub> =+70°C
16 lead CERDIP(derate 10.0mW/°C above +70°C) .....	800mW
Junction Temperature T <sub>J</sub> .....	+150°C
Thermal Resistance, Junction to Case, ΘJC:	
Case Outline 16 lead CERDIP.....	50°C/W
Thermal Resistance, Junction to Ambient, ΘJA:	
Case Outline 16 lead CERDIP.....	100°C/W

### Recommended Operating Conditions

Ambient Operating Range (T <sub>A</sub> ) .....	-55°C to +125°C
Positive Supply Voltage (V <sup>+</sup> ) .....	+5V
Negative Supply Voltage (V <sup>-</sup> ) .....	-5V
V <sub>INL</sub> (max) .....	0.8V
V <sub>INH</sub> (min) .....	2.4V

1/ Signals on NC, NO, COM or IN exceeding V<sup>+</sup> or V<sup>-</sup> are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TABLE 1. ELECTRICAL TESTS: DUAL SUPPLIES**

TEST	Symbol	CONDITIONS -55 °C <=T <sub>A</sub> <= +125°C V <sup>+</sup> =+5V ±10%, V <sup>-</sup> =-5V ±10%, GND=0V, V <sub>INH</sub> =2.4V, V <sub>INL</sub> =0.8V Unless otherwise specified	Group A Subgroup	Device type	Limits Min <u>2/</u>	Limits Max <u>2/</u>	Units
<b>SWITCH</b>							
Analog-Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>	3/	1,2,3	All	V-	V+	V
On-Resistance	r <sub>DS(ON)</sub>	V <sup>+</sup> =+4.5V, V <sup>-</sup> =-4.5V, I <sub>COM</sub> =-10mA, V <sub>NO</sub> or V <sub>NC</sub> =±3.5V	1 2,3	All		30 45	Ω
On-Resistance Matching between Channels	Δr <sub>DS</sub> (ON)	V <sup>+</sup> =+5V, V <sup>-</sup> =-5V, I <sub>COM</sub> =-10mA, V <sub>NO</sub> or V <sub>NC</sub> =±3.0V	1 2,3	All		2.0 4.0	Ω
On-Resistance Flatness	r <sub>FLAT(ON)</sub>	V <sup>+</sup> =+5V, V <sup>-</sup> =-5V, I <sub>COM</sub> =-10mA, V <sub>NO</sub> or V <sub>NC</sub> =±3.0V	1 2,3	All		4.0 6.0	Ω
NO or NC Off Leakage Current	I <sub>NO(OFF)</sub> or I <sub>NC(OFF)</sub>	V <sup>+</sup> =+5.5V, V <sup>-</sup> =-5.5V, V <sub>COM</sub> =±4.5V, V <sub>NO</sub> or V <sub>NC</sub> =±4.5V	1 2,3	All	-0.1 -5.0	0.1 5.0	nA
COM Off Leakage Current	I <sub>COM</sub> (OFF)	V <sup>+</sup> =+5.5V, V <sup>-</sup> =-5.5V, V <sub>COM</sub> =±4.5V, V <sub>NO</sub> or V <sub>NC</sub> =±4.5V	1 2,3	All	-0.1 -5.0	0.1 5.0	nA
COM On Leakage Current	I <sub>COM</sub> (ON)	V <sup>+</sup> =+5.5V, V <sup>-</sup> =-5.5V, V <sub>COM</sub> =±4.5V, V <sub>NO</sub> or V <sub>NC</sub> =±4.5V	1 2,3	All	-0.2 -20.0	0.2 20.0	nA
<b>INPUT</b>							
Input Current/Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 2.4V, all others = 0.8V	1,2,3	All	-0.5	0.5	μA
Input Current/Voltage Low	I <sub>INL</sub>	V <sub>IN</sub> = 0.8V, all others = 2.4V	1,2,3	All	0.5	0.5	μA
<b>SUPPLY</b>							
Power-Supply Range			1,2,3		±8.0	±8.0	V
Positive Supply Current	I <sup>+</sup>	All channels on or off, V <sup>+</sup> =+5.5V, V <sup>-</sup> =-5.5V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
Negative Supply Current	I <sup>-</sup>	All channels on or off, V <sup>+</sup> =+5.5V, V <sup>-</sup> =-5.5V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
<b>DYNAMIC</b>							
Turn-On Time	t <sub>ON</sub>	V <sub>COM</sub> ±3V, Figure 2	9 10,11	All		130 175	ns
Turn-Off Time	t <sub>OFF</sub>	V <sub>COM</sub> ±3V, Figure 2	9 10,11	All		75 100	ns
Break-Before-Make Delay	t <sub>D</sub>	MAX393 only, Figure 3 R <sub>L</sub> =300Ω, C <sub>L</sub> =35pF	9	03	5		ns
Charge Injection	3/ Q	C <sub>L</sub> =1.0nF, V <sub>GEN</sub> =0V, R <sub>GEN</sub> =0Ω Figure 4	9	All		5	pC

**TABLE 2. ELECTRICAL TESTS: SINGLE +5V SUPPLY**

TEST	Symbol	CONDITIONS -55 °C <= T <sub>A</sub> <= +125°C V <sup>+</sup> =+5V ±10%, V <sup>-</sup> =-0V ±10%, GND=0V, V <sub>INH</sub> =2.4V, V <sub>INL</sub> =0.8V Unless otherwise specified	Group A Subgroup	Device type	Limits Min <u>3/</u>	Limits Max <u>3/</u>	Units
<b>SWITCH</b>							
Analog-Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>	<u>3/</u>	1,2,3	All	0	V <sup>+</sup>	V
On-Resistance	r <sub>DS(ON)</sub>	V <sup>+</sup> =+4.5V, I <sub>COM</sub> =-10mA, V <sub>NO</sub> or V <sub>NC</sub> =3.5V	1 2,3	All		60 75	Ω
On-Resistance Matching between Channels <u>4/</u>	Δr <sub>DS</sub> (ON)	V <sup>+</sup> =+5V, I <sub>COM</sub> =-1.0mA, V <sub>NO</sub> or V <sub>NC</sub> =3.0V	1 2,3	All		2.0 4.0	Ω
On-Resistance Flatness <u>3/</u> , <u>5/</u>	r <sub>FLAT(ON)</sub>	V <sup>+</sup> =+5V, I <sub>COM</sub> =-1.0mA, V <sub>NO</sub> or V <sub>NC</sub> =1V, 3V	1 2,3	All		6.0 8.0	Ω
NO or NC Off Leakage Current	I <sub>NO(OFF)</sub> or I <sub>NC(OFF)</sub>	V <sup>+</sup> =+5.5V, V <sub>COM</sub> =0V, V <sub>NO</sub> or V <sub>NC</sub> =4.5V	1 2,3	All	-0.25 -2.5	0.25 2.5	nA
COM Off Leakage Current	I <sub>COM</sub> (OFF)	V <sup>+</sup> =+5.5V, V <sub>COM</sub> =0V, V <sub>NO</sub> or V <sub>NC</sub> =4.5V	1 2,3	All	-0.1 -5.0	0.1 5.0	nA
COM On Leakage Current	I <sub>COM</sub> (ON)	V <sup>+</sup> =+5.5V, V <sub>COM</sub> =5V, V <sub>NO</sub> or V <sub>NC</sub> =4.5V	1 2,3	All	-0.2 -20.0	0.2 20.0	nA
<b>SUPPLY</b>							
Positive Supply Current	I <sup>+</sup>	All channels on or off, V <sup>+</sup> =+5.5V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
Negative Supply Current	I <sup>-</sup>	All channels on or off, V <sup>+</sup> =+5.5V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
<b>DYNAMIC</b>							
Turn-On Time	t <sub>ON</sub>	V <sub>NO</sub> or V <sub>NC</sub> =3V	9 10,11	All		170 240	ns
Turn-Off Time	t <sub>OFF</sub>	V <sub>NO</sub> or V <sub>NC</sub> =3V	9 10,11	All		50 100	ns
Break-Before-Make Delay <u>3/</u>	t <sub>D</sub>	MAX393 only, R <sub>L</sub> =300Ω, C <sub>L</sub> =35pF	9	03	10		ns
Charge Injection <u>3/</u>	Q	C <sub>L</sub> =1.0nF, V <sub>GEN</sub> =0V, R <sub>GEN</sub> =0Ω Figure 4	9	All		5	pC

NOTE 2: This data sheet uses the algebraic convention, where the most negative value is a minimum and the most positive value is a maximum.

NOTE 3: Guaranteed by design at 25°C

NOTE 4: Δr<sub>ON</sub>=Δr<sub>ON(max)</sub>-Δr<sub>ON(min)</sub>.

NOTE 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.

NOTE 6: Leakage testing at single supply is guaranteed by testing with dual supplies.

**FIGURE 2: SWITCHING TIME TEST CIRCUIT:** See Commercial Data Sheet

**FIGURE 3: BREAK-BEFORE-MAKE INTERVAL:** See Commercial Data Sheet

**FIGURE 4: CHARGE INJECTION:** See Commercial Data Sheet

**TABLE 3. ELECTRICAL TESTS: SINGLE +3.3V SUPPLY**

TEST	Symbol	CONDITIONS -55 °C <= T <sub>A</sub> <= +125°C V <sup>+</sup> =+5V ±10%, V <sup>-</sup> =-0V ±10%, GND=0V, V <sub>INH</sub> =2.4V, V <sub>INL</sub> =0.8V Unless otherwise specified	Group A Subgroup	Device type	Limits Min <u>2/</u>	Limits Max <u>2/</u>	Units
<b>SWITCH</b>							
Analog-Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>	3/	1,2,3	All	0	V+	V
Channel On-Resistance	r <sub>DS(ON)</sub>	V <sup>+</sup> =+3V, I <sub>COM</sub> =-1.0mA, V <sub>NO</sub> or V <sub>NC</sub> =1.5V	1 2,3	All		175 275	Ω
<b>SUPPLY</b>							
Positive Supply Current	I <sup>+</sup>	All channels on or off, V <sup>+</sup> =+3.6V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
Negative Supply Current	I <sup>-</sup>	All channels on or off, V <sup>+</sup> =+3.6V, V <sub>IN</sub> =0V or V <sup>+</sup>	1,2,3	All	-1.0	1.0	μA
<b>DYNAMIC</b>							
Turn-On Time 3/	t <sub>ON</sub>	V <sub>NO</sub> or V <sub>NC</sub> =1.5V	9 10,11	All		400 500	ns
Turn-Off Time 3/	t <sub>OFF</sub>	V <sub>NO</sub> or V <sub>NC</sub> =1.5V	9 10,11	All		125 175	ns
Break-Before-Make Delay 3/	t <sub>D</sub>	MAX393 only, R <sub>L</sub> =300Ω, C <sub>L</sub> =35pF	9	03	20		ns
Charge Injection 3/	Q	C <sub>L</sub> =1.0nF, V <sub>GEN</sub> =0V, R <sub>GEN</sub> =0Ω Figure 4	9	All		5	pC

**TRUTH TABLES:**

MAX391	MAX391	MAX392	MAX392		MAX393	MAX393
LOGIC	SWITCH	LOGIC	SWITCH	LOGIC	SWITCHES 1,4	SWITCHES 2,3
0	ON	0	OFF	0	OFF	ON
1	OFF	1	ON	1	ON	OFF

**TERMINAL CONNECTIONS:**

	MAX391	MAX392	MAX393
	J16	J16	
1	IN1	IN1	IN1
2	COM1	COM1	COM1
3	NC1	NO1	NO1
4	V-	V-	V-
5	GND	GND	GND
6	NC4	NO4	NO4
7	COM4	COM4	COM4
8	IN4	IN4	IN4
9	IN3	IN3	IN3
10	COM3	COM3	COM3
11	NC3	NO3	NC3
12	NC	NC	NC
13	V+	V+	V+
14	NC2	NO2	NC2
15	COM2	COM2	COM2
16	IN2	IN2	IN2

<b>ORDERING INFORMATION:</b>		
01	MAX391MJE/883B	16 CDIP
02	MAX392MJE/883B	16 CDIP
03	MAX393MJE/883B	16 CDIP

## QUALITY ASSURANCE

Sampling and inspection procedures shall be in accordance with MIL-Prf-38535, Appendix A as specified in Mil-Std-883.

Screening shall be in accordance with Method 5004 of Mil-Std-883. Burn-in test Method 1015:

1. Test Condition, A, B, C, or D.
2. TA = +125°C minimum.
3. Interim and final electrical test requirements shall be specified in Table 4.

Quality conformance inspection shall be in accordance with Method 5005 of Mil-Std-883, including Groups A, B, C, and D inspection.

Group A inspection:

1. Tests as specified in Table 4.
2. Selected subgroups in Tables 1, Method 5005 of Mil-Std-883 shall be omitted.

Group C and D inspections:

- a. End-point electrical parameters shall be specified in Table 1,2,3.
- b. Steady-state life test, Method 1005 of Mil-Std-883:
  1. Test condition A, B, C, D.
  2. TA = +125°C, minimum.
  3. Test duration, 1000 hours, except as permitted by Method 1005 of Mil-Std-883.

**TABLE 4. ELECTRICAL TEST REQUIREMENTS**

Mil-Std-883 Test Requirements	Subgroups per Method 5005, Table 1
Interim Electric Parameters Method 5004	1
Final Electrical Parameters Method 5005	1*, 2, 3, 9, 10, 11
Group A Test Requirements Method 5005	1, 2, 3, 9, 10, 11
Group C and D End-Point Electrical Parameters Method 5005	1

\* PDA applies to Subgroup 1 only.